



## QUICKSWITCH® PRODUCTS HIGH-SPEED CMOS 10-BIT BUS EXCHANGE SWITCH

**IDTQS32383**

### FEATURES:

- Enhanced N channel FET with no inherent diode to Vcc
- 5Ω bidirectional switches connect inputs to outputs
- Zero ground bounce
- Undershoot clamp diodes on all switch and control pins
- Bus exchange allows nibble swap
- Available in SOIC and QSOP Packages
- 25Ω version for low noise

### APPLICATIONS

- Hot-swapping, hot-docking
- Voltage translation (5V to 3.3V)
- Resource sharing
- Crossbar switching

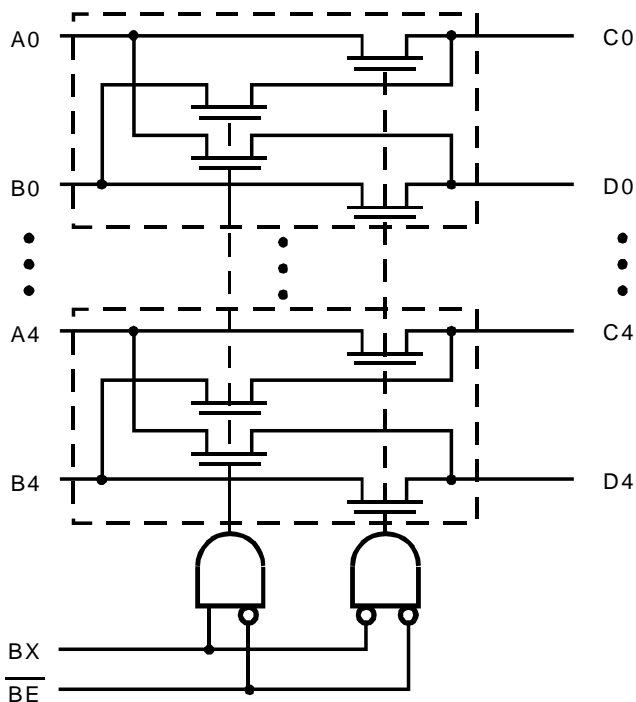
### DESCRIPTION:

The QS32383 provides ten high-speed CMOS TTL-compatible bus switches. The low ON resistance of the QS32383 allows inputs to be connected to outputs without adding propagation delay and without generating additional ground bounce noise. The Bus Enable ( $\overline{BE}$ ) signal turns the switches on. The Bus Exchange (BX) signal provides nibble swap of the AB and CD pairs of signals. This exchange configuration allows byte swapping of buses in systems. It can also be used as a 5-wide 2-to-1 multiplexer and to create low delay barrel shifters, etc.

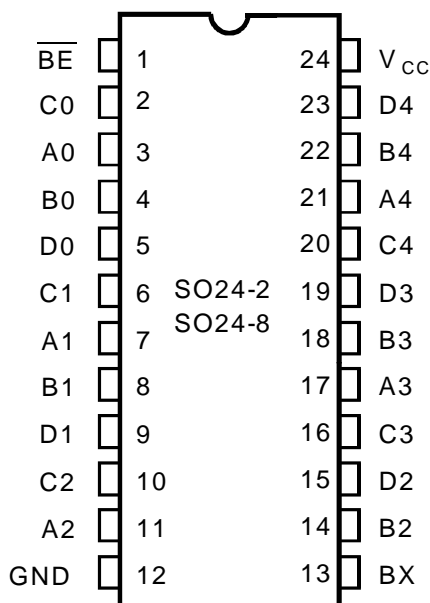
The QS32383 adds an internal 25Ω resistor to reduce reflection noise in high-speed applications. When the switch is closed, it acts as the source termination for the driver connected to it.

The QS32383 is characterized for operation at -40°C to +85°C.

### FUNCTIONAL BLOCK DIAGRAM



## PIN CONFIGURATION



## ABSOLUTE MAXIMUM RATINGS <sup>(1)</sup>

Symbol	Description	Max.	Unit
V <sub>TERM</sub> <sup>(2)</sup>	Supply Voltage to Ground	- 0.5 to +7	V
V <sub>TERM</sub> <sup>(3)</sup>	DC Switch Voltage V <sub>s</sub>	- 0.5 to +7	V
V <sub>TERM</sub> <sup>(3)</sup>	DC Input Voltage V <sub>IN</sub>	- 0.5 to +7	V
V <sub>AC</sub>	AC Input Voltage (pulse width ≤20ns)	-3	V
I <sub>OUT</sub>	DC Output Current	120	mA
P <sub>MAX</sub>	Maximum Power Dissipation (T <sub>A</sub> = 85°C)	0.5	W
T <sub>STG</sub>	Storage Temperature	- 65 to +150	°C

### NOTES:

- Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
- V<sub>CC</sub> Terminals.
- All terminals except V<sub>CC</sub>.

## CAPACITANCE

(T<sub>A</sub> = +25°C, f = 1.0MHz, V<sub>IN</sub> = 0V, V<sub>OUT</sub> = 0V)

Pins	Typ.	Max. <sup>(1)</sup>	Unit
Control Inputs	3	5	pF
Quickswitch Channels (Switch OFF)	5	7	pF

### NOTE:

- This parameter is guaranteed but not production tested.

## PIN DESCRIPTION

Pin Names	I/O	Description
A0-A4, B0-B4	I/O	Buses A, B
C0-C4, D0-D4	I/O	Buses C, D
BE	I	Bus Switch Enable
BX	I	Bus Exchange

## FUNCTION TABLE<sup>(1)</sup>

BE	BX	A0 - A4	B0 - B4	Function
H	X	Hi-Z	Hi-Z	Disconnect
L	L	C0 - C4	D0 - D4	Connect
L	H	D0 - D4	C0 - C4	Exchange

### NOTE:

- H = HIGH Voltage Level  
L = LOW Voltage Level  
X = Don't care  
Z = High-Impedence

## DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Industrial:  $T_A = -40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$ ,  $V_{CC} = 5.0\text{V} \pm 5\%$

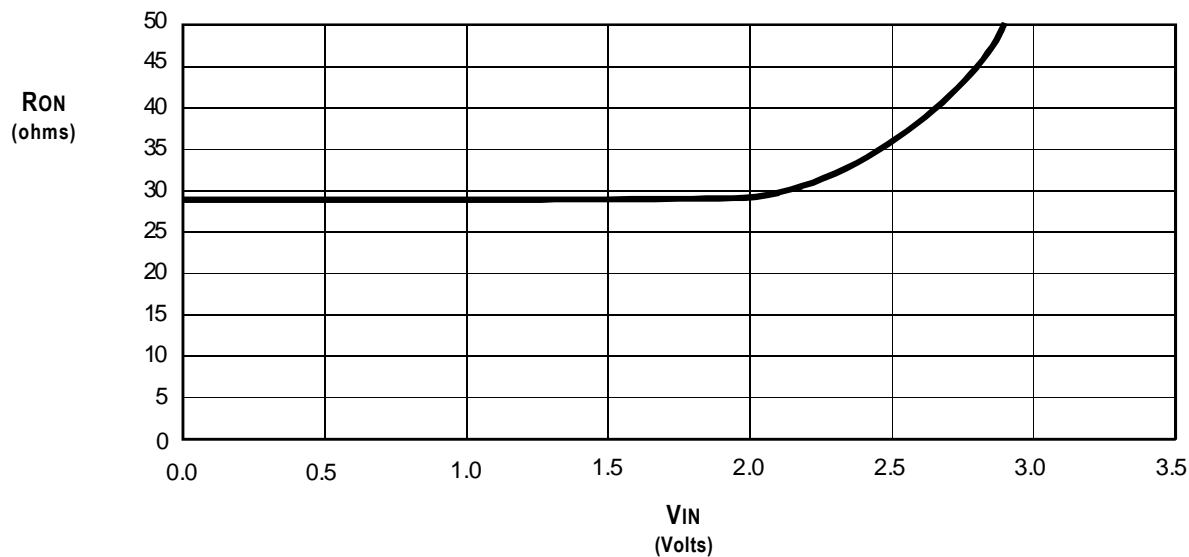
Symbol	Parameter	Test Conditions	Min.	Typ. <sup>(1)</sup>	Max.	Unit
$V_{IH}$	Input HIGH Voltage	Guaranteed Logic HIGH for Control Pins	2	—	—	V
$V_{IL}$	Input LOW Voltage	Guaranteed Logic LOW for Control Pins	—	—	0.8	V
$I_{IN}$	Input Leakage Current (Control Inputs)	$0\text{V} \leq V_{IN} \leq V_{CC}$	—	$\pm 0.01$	$\pm 1$	$\mu\text{A}$
$I_{OZ}$	Off-State Current (Hi-Z)	$0\text{V} \leq V_{OUT} \leq V_{CC}$ , Switches OFF	—	$\pm 0.01$	$\pm 1$	$\mu\text{A}$
$R_{ON}$	Switch ON Resistance	$V_{CC} = \text{Min.}$ , $V_{IN} = 0\text{V}$ , $I_{ON} = 30\text{mA}$	20	28	40	$\Omega$
$R_{ON}$	Switch ON Resistance	$V_{CC} = \text{Min.}$ , $V_{IN} = 2.4\text{V}$ , $I_{ON} = 15\text{mA}$	20	35	48	$\Omega$
$V_P$	Pass Voltage <sup>(2)</sup>	$V_{IN} = V_{CC} = 5\text{V}$ , $I_{OUT} = -5\mu\text{A}$	3.7	4	4.2	V

### NOTES:

1. Typical values are at  $V_{CC} = 5.0\text{V}$ ,  $T_A = 25^{\circ}\text{C}$ .

2. Pass voltage is guaranteed but not production tested.

## TYPICAL ON RESISTANCE vs $V_{IN}$ AT $V_{CC} = 5\text{V}$



## POWER SUPPLY CHARACTERISTICS

Symbol	Parameter	Test Conditions <sup>(1)</sup>	Max.	Unit
I <sub>CCQ</sub>	Quiescent Power Supply Current	V <sub>CC</sub> = Max., V <sub>IN</sub> = GND or V <sub>CC</sub> , f = 0	3	mA
ΔI <sub>CC</sub>	Power Supply Current per Control Input HIGH <sup>(2)</sup>	V <sub>CC</sub> = Max., V <sub>IN</sub> = 3.4V, f = 0	2.5	mA
I <sub>CCD</sub>	Dynamic Power Supply Current per MHz <sup>(3)</sup>	V <sub>CC</sub> = Max., A and B pins open Control Input Toggling at 50% Duty Cycle	0.25	mA/MHz

### NOTES:

- For conditions shown as Min. or Max., use the appropriate values specified under DC Electrical Characteristics.
- Per TLL driven input (V<sub>IN</sub> = 3.4V, control inputs only). A, B, C, and D pins do not contribute to ΔI<sub>CC</sub>.
- This current applies to the control inputs only and represents the current required to switch internal capacitance at the specified frequency. The A and B inputs generate no significant AC or DC currents as they transition. This parameter is guaranteed but not production tested.

## SWITCHING CHARACTERISTICS OVER OPERATING RANGE

T<sub>A</sub> = -40°C to +85°C, V<sub>CC</sub> = 5.0V ± 5%

C<sub>LOAD</sub> = 50pF, R<sub>LOAD</sub> = 500Ω unless otherwise noted.

Symbol	Parameter	Min. <sup>(1)</sup>	Typ.	Max.	Unit
t <sub>PLH</sub> t <sub>PHL</sub>	Data Propagation Delay <sup>(2,3)</sup> AxBx to CxDx, CxDx to AxBx	—	—	1.25 <sup>(3)</sup>	ns
t <sub>PZL</sub> t <sub>PZH</sub>	Switch Turn-on Delay BE to Ax, Bx, Cx, Dx	1.5	—	7.5	ns
t <sub>PLZ</sub> t <sub>PHZ</sub>	Switch Turn-off Delay <sup>(2)</sup> BE to Ax, Bx, Cx, Dx	1.5	—	6.5	ns
t <sub>BX</sub>	Switch Multiplex Delay BX to Ax, Bx, Cx, Dx	1.5	—	7.5	ns

### NOTES:

- Minimums are guaranteed but not production tested.
- This parameter is guaranteed but not production tested.
- The time constant for the switch alone is of the order of 1.25ns for C<sub>L</sub> = 50pF. The bus switch contributes no propagation delay other than the RC delay of the ON resistance of the switch and the load capacitance. Since this time constant is much smaller than the rise and fall times of typical driving signals, it adds very little propagation delay to the system. Propagation delay of the bus switch, when used in a system, is determined by the driving circuit on the driving side of the switch and its interaction with the load on the driven side.

## ORDERING INFORMATION

IDTQS	XXXXX	XX	X		
	Device Type	Package	Process		
				Blank	Industrial (-40°C to +85°C)
				SO	Small Outline IC (SO24-2)
				Q	Quarter Size Outline Package (SO24-8)
				32383	High Speed CMOS 10-Bit Bus Exchange Switch



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